

## LS4416 N-CHANNEL JFET



## Linear Systems replaces discontinued Siliconix 2N4416 The LS4416 is a N-Channel high frequency JFET amplifier

The LS4416 N-channel JFET is designed to provide high-performance amplification at high frequencies.

The SOT-23 package provides ease of manufacturing, and a lower cost assembly option.

## LS4416 Benefits:

- Wideband High Gain
- Very High System Sensitivity
- High Quality of Amplification
- High-Speed Switching Capability
- High Low-Level Signal Amplification

## LS4416 Applications:

- High-Frequency Amplifier / Mixer
- Oscillator
- Sample-and-Hold
- Very Low Capacitance Switches

FEATURES						
DIRECT REPLACEMENT FOR SILICONIX 2N4416						
EXCEPTIONAL GAIN (400 MHz)	10dB (min)					
VERY LOW NOISE FIGURE (400 MHz)	RY LOW NOISE FIGURE (400 MHz) 4dB (max)					
VERY LOW DISTORTION						
HIGH AC/DC SWITCH OFF-ISOLATION						
ABSOLUTE MAXIMUM RATINGS						
@ 25°C (unless otherwise noted)						
Maximum Temperatures						
Storage Temperature	-65°C to +200°C					
Operating Junction Temperature	-55°C to +135°C					
Maximum Power Dissipation						
Continuous Power Dissipation	300mW					
MAXIMUM CURRENT						
Gate Current (Note 1)	10mA					
MAXIMUM VOLTAGES	2					
Gate to Drain or Gate to Source	-30V					

LS4416 ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	MIN	TYP.	MAX	UNITS	CONDITIONS
$BV_{GSS}$	Gate to Source Breakdown Voltage	-30		1	V	$I_{G} = -1\mu A$ , $V_{DS} = 0V$
$V_{GS(off)}$	Gate to Source Cutoff Voltage			-6	V	$V_{DS} = 15V, I_{D} = 1nA$
I <sub>DSS</sub>	Gate to Source Saturation Current	5	4-	<b>1</b> 5	mA	$V_{DS} = 15V, V_{GS} = 0V$
I <sub>GSS</sub>	Gate <mark>Le</mark> akage Current			-1.0	nA	$V_{GS} = -15V, V_{DS} = 0V$
g <sub>fs</sub>	Forward <mark>T</mark> rans <mark>co</mark> nd <mark>uc</mark> tance	4500		750 <mark>0</mark>	μS	$V_{DS} = 15V, V_{GS} = 0V, f = 1kHz$
g <sub>os</sub>	Outp <mark>ut</mark> Con <mark>d</mark> uct <mark>an</mark> ce			50	μS	
C <sub>iss</sub>	Input Capacitance <sup>2</sup>			0.8	pF	
$C_{rss}$	Reverse Transfer Capacitance <sup>2</sup>			4	pF	$V_{DS} = 15V, V_{GS} = 0V, f = 1MHz$
C <sub>oss</sub>	Output Capacitance <sup>2</sup>			2	pF	
e <sub>n</sub>	Equivalent Input Noise Voltage		6		nV/√Hz	$V_{DS} = 10V$ , $V_{GS} = 0V$ , $f = 1kHz$

LS4416 HIGH FREQUENCY ELECTRICAL CHARACTERISTICS @ 25°C (unless otherwise noted)

SYMBOL	CHARACTERISTIC	100 Mhz		400 Mhz		UNITS	CONDITIONS	
		MIN	MAX	MIN	MAX			
g <sub>Iss</sub>	Input Conductance		100		1000			
b <sub>Iss</sub>	Input Susceptance <sup>2</sup>		2500		10000	c	$V_{DS} = 15V, V_{GS} = 0V$	
g <sub>oss</sub>	Output Conductance		75		100	μS	V <sub>DS</sub> - 13V, V <sub>GS</sub> - UV	
b <sub>oss</sub>	Output Susceptance <sup>2</sup>		1000		4000			
G <sub>fs</sub>	Forward Transconductance			4000				
G <sub>ps</sub>	Power Gain <sup>2</sup>	18		10		dB	$V_{DS} = 15V$ , $I_D = 5mA$	
NF	Noise Figure <sup>2</sup>		2		4		$V_{DS} = 15V$ , $I_D = 5mA$ , $R_G = 1k\Omega$	
NOTES	1. Absolute manifesture and limiting column place which ICAAAC complete life, many her imprised							

1. Absolute maximum ratings are limiting values above which LS4416 serviceability may be impaired.

2. Not production tested, guaranteed by design

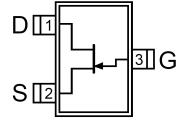
Micross Components Europe



Available Packages:

LS4416 in SOT-23 LS4416 in bare die.

SOT-23 (Top View)



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Please contact Micross for full package and die dimensions

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